



### **FEATURES**

- No opto feedback
- Patents Pending
- Optimised bipolar output voltages for IGBT/ SiC & Mosfet gate drives
- Configurable dual outputs for all gate drive applications: +15V/-5V, +15V/-10V & +20V/-5V outputs
- Reinforced insulation to UL60950 recognised
- ANSI/AAMI ES60601-1 1MOPP/2MOOPs recognised
- Characterised dv/dt immunity 80kV/µs at 1.6kV
- Characterised partial discharge performance
- 5.2kVDC isolation test voltage 'Hi Pot Test'
- Ultra low coupling capacitance 15pF
- DC link voltage 3kVDC
- 5V, 12V & 24V input voltages
- 105°C operating temperature

### **PRODUCT OVERVIEW**

Offering configurable dual output voltages of +15V/-10V, +20V/-5V and +15V/-5V, the MGJ3 series of DC-DC converters is ideal for powering 'high side' and 'low side' gate drive circuits for IGBTs, Silicon and Silicon Carbide Mosfets in bridge circuits. A choice of asymmetric output voltages allows optimum drive levels for best system efficiency and EMI. The MGJ3 series is characterised for high isolation and dv/dt requirements commonly seen in bridge circuits used in motor drives and inverters. A disable/frequency synchronisation pin simplifies EMC filter design. The MGJ3 protection features include short circuit protection and overload protection.



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### 5.2kVDC Isolated 3W Gate Drive SM DC-DC Converters

SELECTION GUIDE								
				Output 1			Output 2	
Order Code <sup>1</sup>	Input Voltage Range	Typical Application	Rated Output Voltage	Rated Output Current	Output Power	Rated Output Voltage	Rated Output Current	Output Power
	V	See page 3	V	mA	W	V	mA	W
MGJ3T05150505MC	4.5 - 9	IGBT	+15	120	1.8	-10	120	1.2
MGJ3T12150505MC	9 - 18	IGBT	+15	120	1.8	-10	120	1.2
MGJ3T24150505MC	18 - 36	IGBT	+15	120	1.8	-10	120	1.2
MGJ3T05150505MC	4.5 - 9	SiC	+20	120	2.4	-5	120	0.6
MGJ3T12150505MC	9 - 18	SiC	+20	120	2.4	-5	120	0.6
MGJ3T24150505MC	18 - 36	SiC	+20	120	2.4	-5	120	0.6
MGJ3T05150505MC	4.5 - 9	MOSFET	+15	150	2.25	-5	150	0.75
MGJ3T12150505MC	9 - 18	MOSFET	+15	150	2.25	-5	150	0.75
MGJ3T24150505MC	18 - 36	MOSFET	+15	150	2.25	-5	150	0.75

### **SELECTION GUIDE (Continued)**

				Outp	out 1			Outp	out 2	
Order Code <sup>1</sup>	Input Voltage Range	Typical Application	Load Regulation (Typ) <sup>3</sup>	Load Regulation (Max) <sup>3</sup>	Ripple & Noise $(Typ)^2$	Ripple & Noise (Max) <sup>2</sup>	Load Regulation (Typ) <sup>3</sup>	Load Regulation (Max) <sup>3</sup>	Ripple & Noise $(Typ)^2$	Ripple & Noise (Max) <sup>2</sup>
	V	See page 3	9	6	mV	р-р	9	6	mV	р-р
MGJ3T05150505MC	4.5 - 9	IGBT	3	10	69	200	3	10	98	150
MGJ3T12150505MC	9 - 18	IGBT	3	10	85	200	3	10	108	150
MGJ3T24150505MC	18 - 36	IGBT	3	10	83	200	3	10	104	150
MGJ3T05150505MC	4.5 - 9	SiC	3	10	118	275	3	10	49	75
MGJ3T12150505MC	9 - 18	SiC	3	10	139	275	3	10	54	75
MGJ3T24150505MC	18 - 36	SiC	3	10	135	275	3	10	52	75
MGJ3T05150505MC	4.5 - 9	MOSFET	3	10	69	200	3	10	49	75
MGJ3T12150505MC	9 - 18	MOSFET	3	10	85	200	3	10	54	75
MGJ3T24150505MC	18 - 36	MOSFET	3	10	83	200	3	10	52	75

1. Components are supplied in tape and reel packaging, please refer to package specification section. Orderable part numbers are MGJ3TXX150505MC-R7 (23 pieces per reel), or MGJ3TXX150505MC-R13 (92 pieces per reel).

See ripple & noise test method.
 Between 75% and 100% rated output current.

All specifications typical at T<sub>A</sub>=25°C, nominal input voltage and rated output current unless otherwise specified.

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# **MGJ3 Series**

5.2kVDC Isolated 3W Gate Drive SM DC-DC Converters

SELECTION GUIDE (C	ontinuea)								
Order Code	Nominal Input Voltage	Input Current at Rated Load	Efficiency (Min)	Efficiency (Typ)	Isolation Capacitance	217	MTTF		5
	Nom	Inpu at R		5 5	Cap	MIL		Telecordia	5
	V	mA		ю	pF		kHrs		
MGJ3T05150505MC	5	760	75	78.5	15	889		666	j2
MGJ3T12150505MC	12	310	78	82	15	939		659	96
MGJ3T24150505MC	24	155	77	81	15	915		659	96
INPUT CHARACTERIS	STICS								
Parameter			ditions			Min.	Тур.	Max.	Unit
Voltago rongo			iput types			4.5	5	9	- v
Voltage range			input types input types			9 18	12 24	18 36	V
			on threshold MGJ3T05	5		10	4.1	- 30	
			off threshold MGJ3T05				3.0		-
			on threshold MGJ3T12				8.1		-
Under voltage lock out			off threshold MGJ3T12				7.5		V
		Turn	on threshold MGJ3T24	1			16.7		-
			off threshold MGJ3T24				16.1		-
		5V ir	put types				18		
Input ripple current		12V	input types				12		m/
		24V	input types				9		p-p
OUTPUT CHARACTER	ISTICS								
Parameter			litions			Min.	Тур.	Max.	Uni
Minimum load					to 6V and 16V respective	ely 10			%
Voltage set point accuracy	/		inal output voltages are	e at 75% loading			±4		%
Line regulation			line to high line	100 50% ( 1			10	2	%
Transient response			deviation (50-100% & ng time	100-50% load swing)			1.2 0.25		%Va
ISOLATION CHARACT	FRISTICS	Ootti	ng tino				0.20		
Parameter	LIIISTICS	Conc	litions			Min.	Тур.	Max.	Unit
Isolation test voltage		Flash	tested for 1 second			5200			VD
isolation test voltage		Quali	fication tested for 1 mi	inute		5200			VD
Resistance			= 1kVDC			100			GΩ
Continuous barrier withs		Non-	safety barrier application	on				3000	V
GENERAL CHARACTE Parameter	RISTICS	Con	litions			Min.	Tun	Max.	Unit
Switching frequency		COIRC	1110115			IVIIII.	Typ. 100	IVIdX.	kHz
TEMPERATURE CHAF	RACTERISTICS								
Parameter		Conc	litions			Min.	Тур.	Max.	Uni
Operation			derating graphs			-40		105	
Storage						-50		125	°C
Product temperature rise		100%	6 Load, Nom Vℕ, Still Ai	ir			18		
ABSOLUTE MAXIMU	M RATINGS								
Short-circuit protection						Continu	ous		
nput voltage, MGJ3 5V i	1 11					12V			
Input voltage, MGJ3 12V						20V			
Input voltage, MGJ3 24V	input types					40V			

1. Calculated using MIL-HDBK-217 FN2 and Telecordia SR-332 calculation model with nominal input voltage at full load.

### **MGJ3 Series**

### 5.2kVDC Isolated 3W Gate Drive SM DC-DC Converters

#### **TECHNICAL NOTES**

#### **ISOLATION VOLTAGE**

'Hi Pot Test', 'Flash Tested', 'Withstand Voltage', 'Proof Voltage', 'Dielectric Withstand Voltage' & 'Isolation Test Voltage' are all terms that relate to the same thing, a test voltage, applied for a specified time, across a component designed to provide electrical isolation, to verify the integrity of that isolation.

Murata Power Solutions MGJ3 series of DC-DC converters are all 100% production tested at 5.2kVDC for 1 second and qualification tested at 5.2kVDC for 1 minute.

A question commonly asked is, "What is the continuous voltage that can be applied across the part in normal operation?"

When the insulation in the MGJ3 series is not used as a safety barrier , i.e. provides functional isolation only, continuous or switched voltages across the barrier up to 3kV are sustainable. Long term reliability testing at these voltages continues. Peak Inception voltages measured were in excess of 3.5kV when testing for partial discharge in accordance with IEC 60270. Please contact Murata for further information.

The MGJ3 series has been recognised by Underwriters Laboratory to 250 Vrms Reinforced Insulation, please see safety approval section below.

#### **REPEATED HIGH-VOLTAGE ISOLATION TESTING**

It is well known that repeated high-voltage isolation testing of a barrier component can actually degrade isolation capability, to a lesser or greater degree depending on materials, construction and environment. We therefore strongly advise against repeated high voltage isolation testing, but if it is absolutely required, that the voltage be reduced by 20% from specified test voltage.

#### SAFETY APPROVAL

#### ANSI/AAMI ES60601-1

The MGJ3 series is recognised to ANSI/AAMI ES60601-1 and provides 1 MOPP (Means Of Patient Protection) and 2 MOOP (Means Of Operator Protection) based upon a working voltage of 250 Vrms max, between Primary and Secondary.

#### UL 60950

The MGJ3 series has been recognised by Underwriters Laboratory (UL) to UL 60950 for reinforced insulation to a working voltage of 250Vrms with a maximum measured product operating temperature of 105°C.

Creepage and clearance 7mm.

#### FUSING

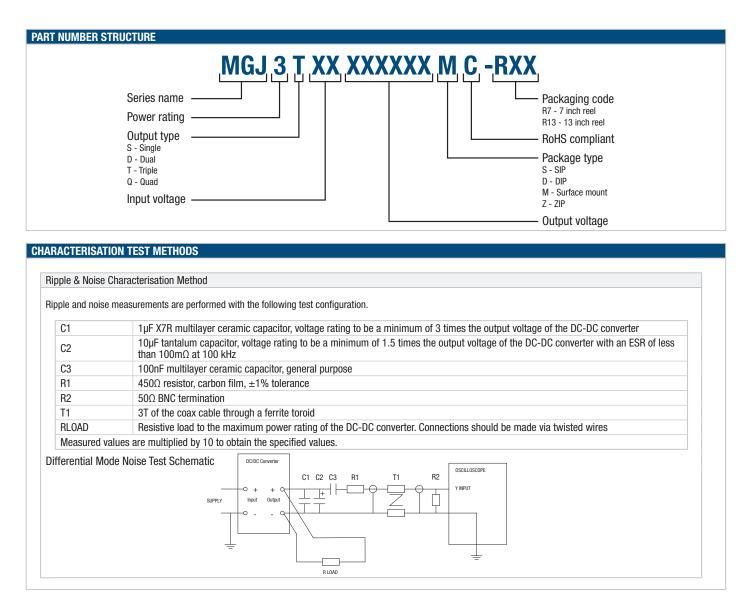
The MGJ3 Series of converters are not internally fused so to meet the requirements of UL an anti-surge input line fuse should always be used with ratings as defined below. Input Voltage, 5V 2A Input Voltage, 12V 1A Input Voltage, 24V 0.5A All fuses should be UL recognised. 125V rated.

#### **RoHS COMPLIANCE, MSL AND PSL INFORMATION**



This series is compatible with RoHS soldering systems with a peak reflow solder temperature of 245°C and Time Above Liquidus for 90 seconds. as per J-STD-020D.1. The pin termination finish on this product series is Gold with Nickel Pre-plate. The series is backward compatible with Sn/Pb soldering systems. The series has a Moisture Sensitivity Level (MSL) 1. Samples of the product series were tested in accordance with the conditioning described for MSL level 1 in IPS/J-STD-020D.1. The product series passed electrical tests, co-planarity and visual inspection criteria.

# **MGJ3 Series**



### **MGJ3 Series**

### 5.2kVDC Isolated 3W Gate Drive SM DC-DC Converters

#### **APPLICATION NOTES**

#### Disable/Frequency synchronisation

#### Please refer to application notes for further information

·····		Min	Тур	Max	Units
	Pull Down Current		0.5		mA
Disable/Sync <sup>1</sup>	Input High	2		60	V
	Input Low	-0.6		0.8	V
Synchronisation	Frequency Range	90	100	110	kHz
Synchionisation	Duty Cycle	25		75	%

The Disable/Synchronization pin has three modes:

- 1. When a DC logic low voltage is applied to this pin the MGJ3 is disabled and enters a low quiescent current sleep mode.
- When this pin is left floating or a DC logic high (CMOS/TTL compatible) voltage is applied the MGJ3 is enabled and operates at the programmed frequency of 100kHz
- When a square wave of between 90kHz and 110kHz is applied to this pin, the switcher operates at the same frequency as the square wave. The falling edge of the square wave corresponds to the start of the switching cycle. If the signal is slower than 25Hz, it will be interpreted as enabling and disabling the part. If the MGJ3 is disabled, it must be disabled for 7 clock cycles before being re-enabled.

Note: The Dis/Sync pin is a high impedance TTL input and can be triggered by noise from external circuits if not treated carefully.

Please refer to "LAYOUT CONSIDERATIONS" and "SYNCHRONISATION CIRCUIT" for further details.

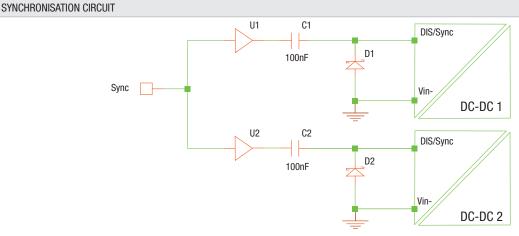
Click here for general guidance for gate drive applications.

#### LAYOUT CONSIDERATIONS

Unlike standard isolated DC-DC products the MGJ3 series has been designed specifically for high side gate drive applications where the outputs are being driven to a high voltage at a very high dV/dT. This is possible due to minimum transformer coupling capacitance and considered circuit design regarding common mode transient immunity. It is important that these few simple pcb layout guidelines are implemented so as not to compromise the performance of the DC-DC and that of the overall system.

- The keep clear area shown must not have any copper traces even on internal layers. This is not only to avoid compromising the creepage and clearance distance but also to minimise capacitive coupling between the noisy output circuits and input control circuits. In general it is good practice to maintain the same band of clearance area running directly through both the DC-DC and the gate drive isolators as shown so that input and output are kept separate and do not overlap or mesh together at any point.
- 2. A top layer ground plane copper area connected to --Vin can be used to create an effective screen to the underside of the MGJ3 series and can also be used as a guard ring for the gate drive isolator inputs. If the Dis/Synch pin is being used then it is imperative that it follows a route covered by this screen to avoid differential pick up. It should also be kept as short as possible.

Please refer to "PACKAGE SPECIFICATIONS" for recommended layout.



- 1. A suggested synchronisation circuit is shown. C1 and C2 are 100nF capacitors. D1 and D2 are schottky diodes. The capacitive coupling and close connected diode ensures that a transition from high to low is seen at the input pin even in a noisy environment or when there is a slight ground shift between devices.
- If the Dis/Sync pin is not used for synchronisation, then a 22nF capacitor can be added between the Dis/Sync pin and –Vin pin to improve noise immunity. If the
  functionality of Dis/Sync is not required, the Dis/Sync pin can be connected directly to the +Vin pin to improve noise immunity.
- 3. One very effective method to reduce common mode transient interference is to add a common mode filter to the DC input. It may only be necessary to add one before splitting the supply to each DC-DC.

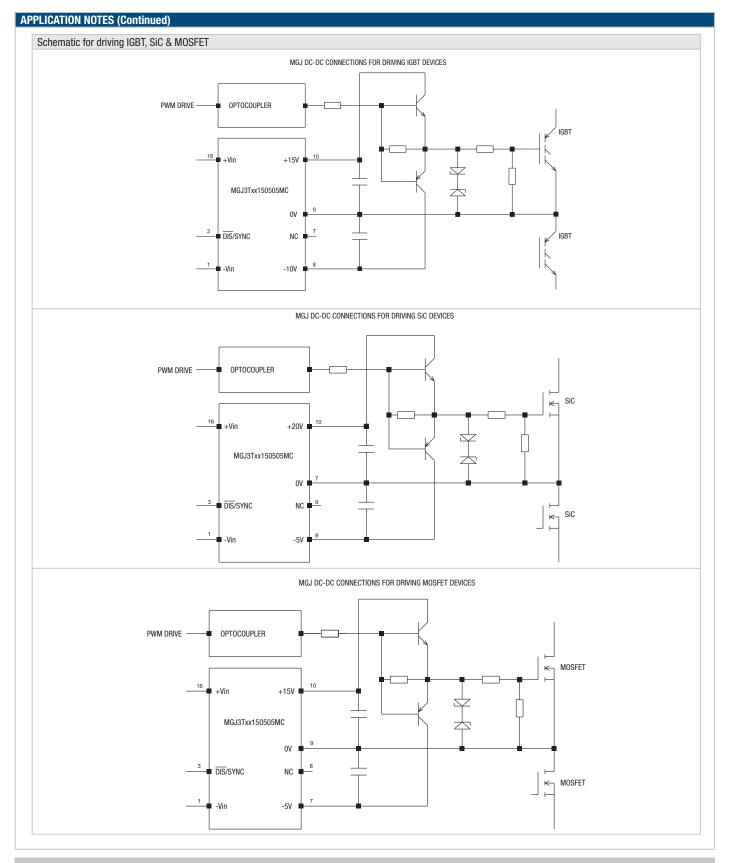
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# **MGJ3 Series**

ical start up times for this se	eries, with no additional	output capacitance are:	Output capacitance must not	exceed:
	Start-up times		O had Malla an	Maximum output
Part No.	ms		Output Voltage	capacitance
MGJ3T05150505MC	15		V	μF
MGJ3T12150505MC	15		15	120
MGJ3T24150505MC	15		5	220
Terminal		IGRT	SIC	MOSEET
Terminal (P10)		IGBT +15V	SIC +20V	MOSFET +15V
(P10) 15V Output		IGBT +15V 0.12A	SIC +20V 0.12A	MOSFET +15V 0.15A
(P10)		+15V	+20V	+15V
(P10) 15V Output (P9) 15V Return		+15V 0.12A	+20V 0.12A	+15V 0.15A

# **MGJ3 Series**

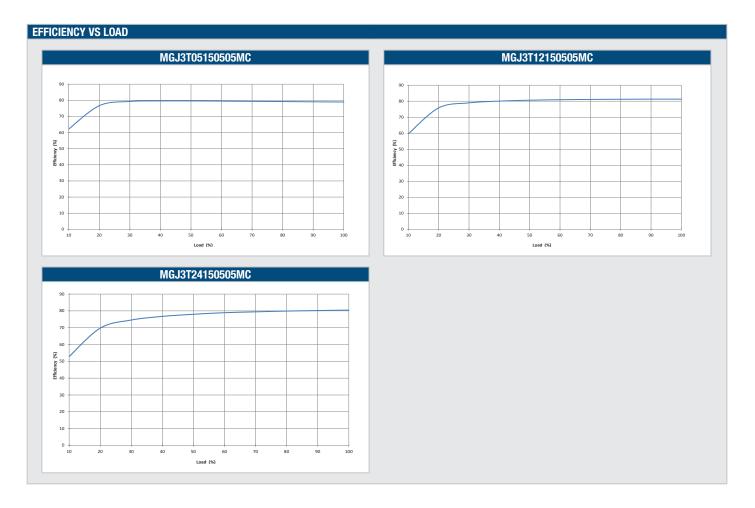
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# **MGJ3 Series**

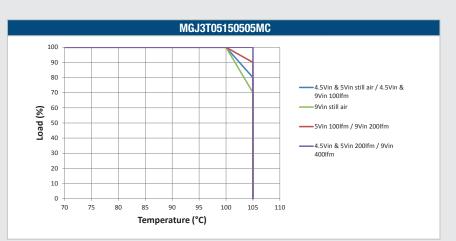


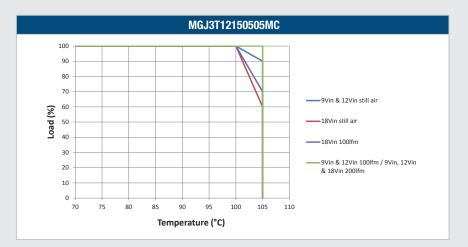
### **MGJ3 Series**

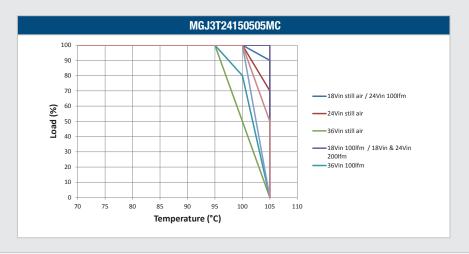
5.2kVDC Isolated 3W Gate Drive SM DC-DC Converters

### **DERATING GRAPHS**

Derating curves are based on IPC-9592. With no derating some components may be operating at the manufacturers maximum temperature ratings.

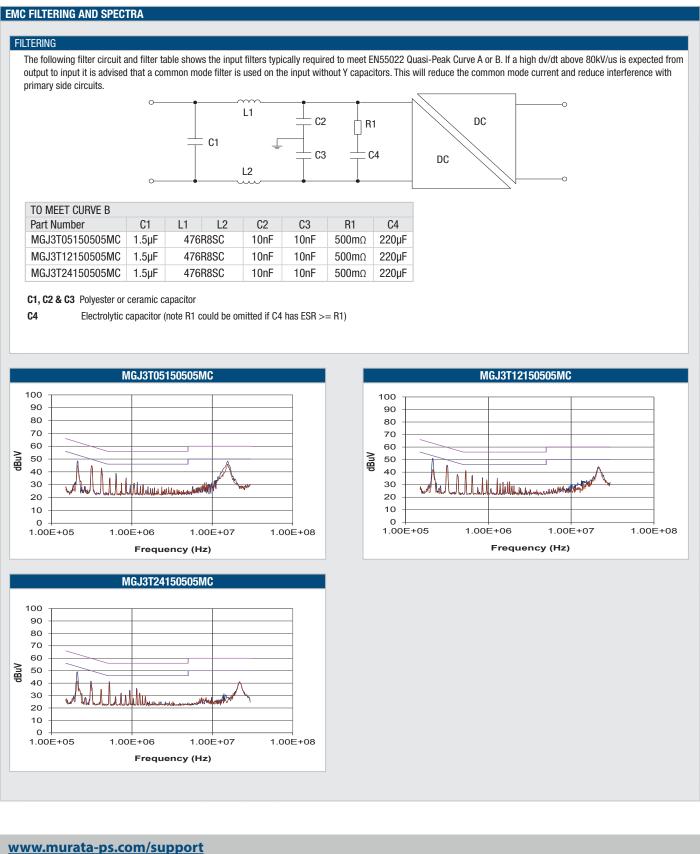






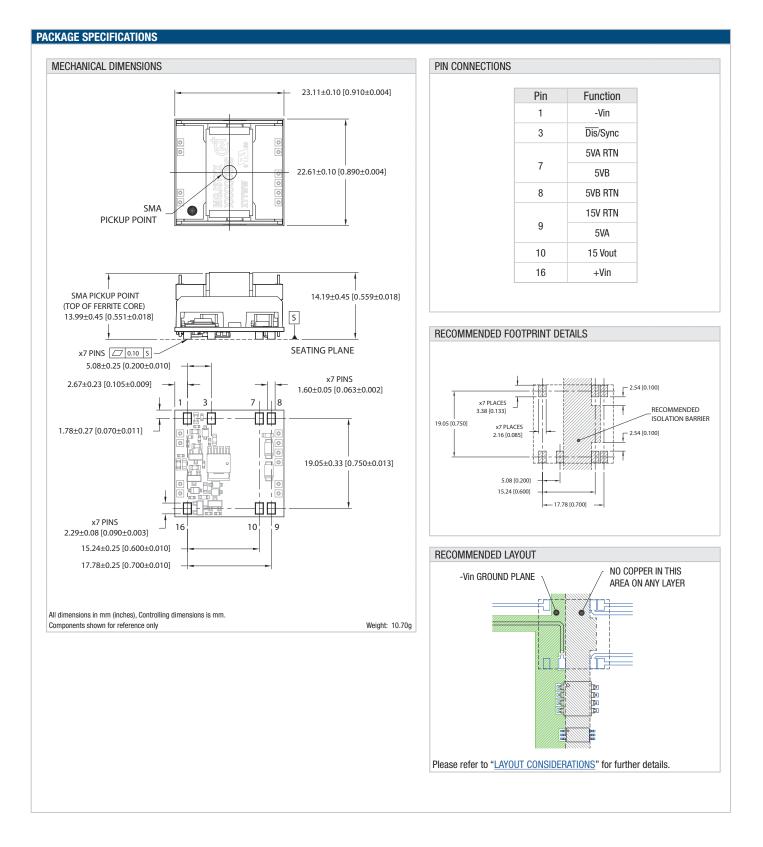
# **MGJ3 Series**

### 5.2kVDC Isolated 3W Gate Drive SM DC-DC Converters



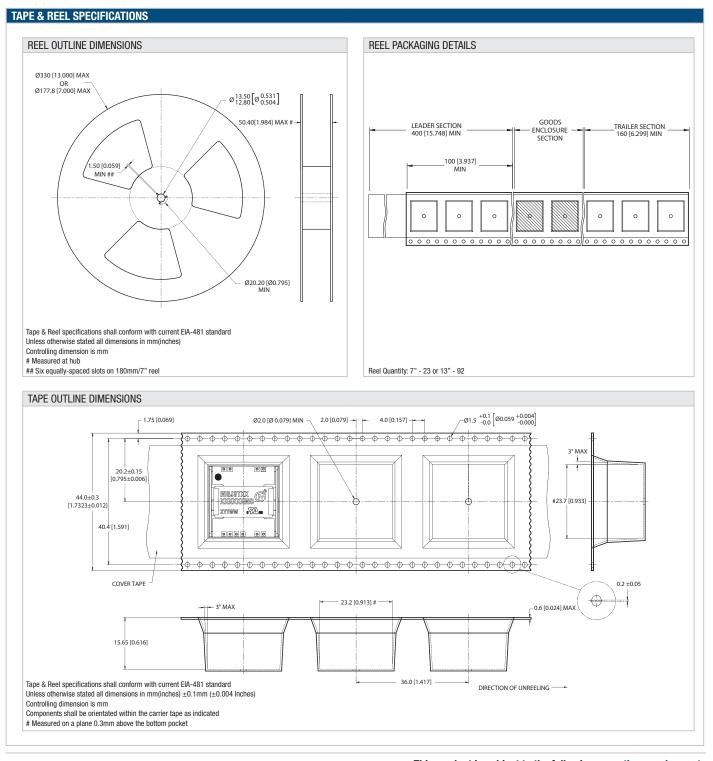
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# **MGJ3 Series**



# **MGJ3 Series**

5.2kVDC Isolated 3W Gate Drive SM DC-DC Converters



This product is subject to the following <u>operating requirements</u> and the <u>Life and Safety Critical Application Sales Policy</u>: Refer to: <u>http://www.murata-ps.com/requirements/</u>

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<u>MGJ3T24150505MC-R13</u> <u>MGJ3T12150505MC-R13</u> <u>MGJ3T05150505MC-R13</u> <u>MGJ3T12150505MC-R7</u> MGJ3T24150505MC-R7 MGJ3T05150505MC-R7